SWITCHMODE Series NPN Silicon Power Transistor

- ... designed for high speed, high current, high power applications.
- High DC current gain:

hFE min. = 20 at I_C = 12 A

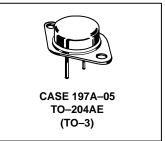
• Low VCE(sat), VCE(sat) max. = 0.6 V at IC = 8 A

Very fast switching times:

TF max. = $0.4 \mu s$ at IC = 25 A

BUV21

40 AMPERES
NPN SILICON
POWER
METAL TRANSISTOR
200 VOLTS
250 WATTS



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|------------|------------|
| Collector–Emitter Voltage | VCEO(sus) | 200 | Vdc |
| Collector–Base Voltage | V _{CBO} 250 | | Vdc |
| Emitter–Base Voltage | VEBO | 7 | Vdc |
| Collector–Emitter Voltage (V _{BE} = -1.5 V) | VCEX | 250 | Vdc |
| Collector–Emitter Voltage (R _{BE} = 100 Ω) | VCER | 240 | Vdc |
| Collector–Current — Continuous — Peak (pw ≤ 10 ms) | IC ICM | 40 50 | Adc Apk |
| Base-Current continuous | lВ | 8 | Adc |
| Total Power Dissipation @ T _C = 25°C | PD | 150 | Watts |
| Operating and Storage Junction Temperature Range | T _J , T _{Stg} | -65 to 200 | °C |

THERMAL CHARACTERISTICS

| ı | Characteristic | Symbol | Max | Unit |
|---|--------------------------------------|--------|-----|------|
| ı | Thermal Resistance, Junction to Case | θЈС | 0.7 | °C/W |

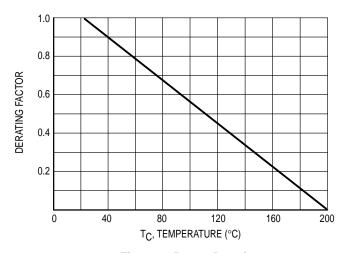


Figure 1. Power Derating

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BUV21

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit | |
|---|--|-----------------|----------|-------------|------|--|
| OFF CHARACTERISTICS ¹ | | | | | | |
| Collector–Emitter Sustaining Voltage (I _C = 200 mA, I _B = 0, L = 25 mH) | | VCEO(sus) | 200 | | Vdc | |
| Collector Cutoff Current at Reverse Bias: (V _{CE} = 250 V, V _{BE} = -1.5 V) (V _{CE} = 250 V, V _{BE} = -1.5 V, T _C = 125°C) | | ICEX | | 3.0 12.0 | mAdc | |
| Collector–Emitter Cutoff Current (V _{CE} = 160 V) | | ICEO | | 3.0 | mAdc | |
| Emitter–Base Reverse Voltage (I _E = 50 mA) | V _{EBO} | 7 | | V | | |
| Emitter–Cutoff Current (V _{EB} = 5 V) | IEBO | | 1.0 | mAdc | | |
| SECOND BREAKDOWN | | | | • | | |
| Second Breakdown Collector Cur (V _{CE} = 20 V, t = 1 s) (V _{CE} = 140 V, t = 1 s) | I _{S/b} | 12 0.15 | | Adc | | |
| ON CHARACTERISTICS ¹ | | | | | | |
| DC Current Gain (I _C = 12 A, V _{CE} = 2 V) (I _C = 25 A, V _{CE} = 4 V) | | hFE | 20 10 | 60 | | |
| Collector–Emitter Saturation Voltage (I _C = 12 A, I _B = 1.2 A) (I _C = 25 A, I _B = 3 A) | | VCE(sat) | | 0.6 1.5 | Vdc | |
| Base–Emitter Saturation Voltage (I _C = 25 A, I _B = 3 A) | V _{BE(sat)} | | 1.5 | Vdc | | |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Current Gain – Bandwidth Product $(V_{CE} = 15 \text{ V}, I_{C} = 2 \text{ A}, f = 4 \text{ MHz})$ | | fT | 8.0 | | MHz | |
| SWITCHING CHARACTERISTICS | (Resistive Load) | | | - | - | |
| Turn-on Time | | t _{on} | | 1.0 | μs | |
| Storage Time | orage Time $(I_C = 25 \text{ A, } I_{B1} = I_{B2} = 3 \text{ A,} V_{CC} = 100 \text{ V, } R_C = 4 \Omega)$ | | | 1.8 | 1 | |
| Fall Time | | t _f | | 0.4 | 1 | |

¹ Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

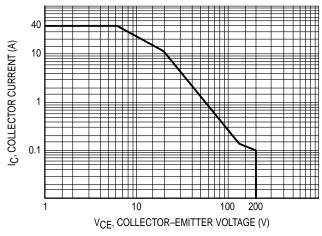


Figure 2. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{\text{C}} - V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_C = 25^{\circ}C$, $T_{J(pk)}$ is variable depending on power level. Second breakdown limitations do not derate the same as thermal limitations.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

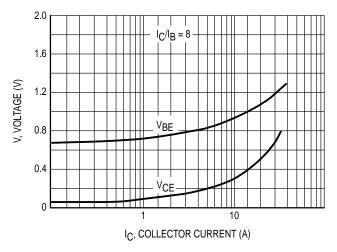


Figure 3. "On" Voltages

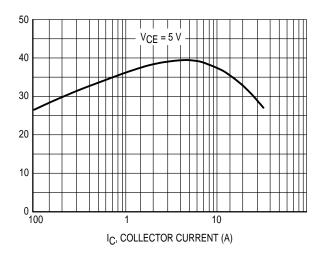


Figure 4. DC Current Gain

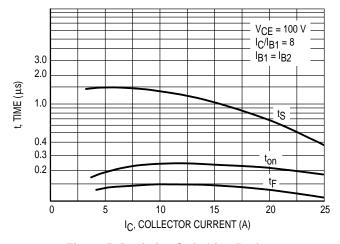
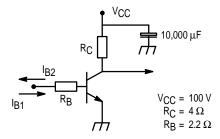


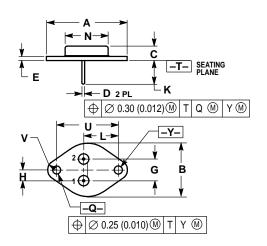
Figure 5. Resistive Switching Performance



R_C – R_B: Non inductive resistances

Figure 6. Switching Times Test Circuit

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 5M 1982
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

| | INCHES | | MILLIMETERS | | |
|-----|--------------------|-------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 1.530 REF | | 38.86 REF | | |
| В | 0.990 | 1.050 | 25.15 | 26.67 | |
| С | 0.250 | 0.335 | 6.35 | 8.51 | |
| D | 0.057 | 0.063 | 1.45 | 1.60 | |
| Е | 0.060 | 0.070 | 1.53 | 1.77 | |
| G | 0.430 BSC 10.92 BS | | BSC | | |
| Н | 0.215 BSC | | 5.46 BSC | | |
| K | 0.440 | 0.480 | 11.18 | 12.19 | |
| L | 0.665 BSC | | 16.89 BSC | | |
| N | 0.760 | 0.830 | 19.31 | 21.08 | |
| Q | 0.151 | 0.165 | 3.84 | 4.19 | |
| U | 1.187 | BSC | 30.15 BSC | | |
| ٧ | 0.131 | 0.188 | 3.33 | 4.77 | |

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

CASE 197A-05 TO-204AE (TO-3) ISSUE J

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